

NCE N-Channel Super Trench II Power MOSFET

Description

The series of devices uses **Super Trench II** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{\text{DS(ON)}}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

Application

- DC/DC Converter
- ●Ideal for high-frequency switching and synchronous rectification

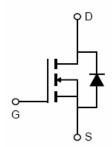
General Features

- V_{DS} =85V, I_D =90A $R_{DS(ON)}$ =5.7m Ω , typical (TO-220)@ V_{GS} =10V
- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 175 °C operating temperature
- Pb-free lead plating

100% UIS TESTED! 100% ΔVds TESTED!

TO-220





Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP065N85	NCEP065N85	TO-220	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	85	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	90	А
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	66	Α
Pulsed Drain Current	I _{DM}	360	Α
Maximum Power Dissipation	P _D	120	W
Derating factor		0.80	W/°C
Single pulse avalanche energy (Note 5)	E _{AS}	460	mJ
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}$ C

Thermal Characteristic

Thermal Resistance, Junction-to-Case (Note 2)	$R_{ heta JC}$	1.25	°C/W	l
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Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	col Condition		Min	Тур	Max	Unit
Off Characteristics				•			
Drain-Source Breakdown Voltage	BV _{DSS}	V_{GS} =0V I_D =250 μ A		85		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =85V,V _{GS} =0V		-	-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V		-	-	±100	nA
On Characteristics (Note 3)							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS},I_{D}=2$	250µA	2.0	3.0	4.0	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =45A	TO-220	-	5.7	6.5	mΩ
Forward Transconductance	g FS	V _{DS} =5V,I _D =45A			60	-	S
Dynamic Characteristics (Note4)							
Input Capacitance	C _{lss}	V _{DS} =40V,V _{GS} =0V, F=1.0MHz		-	3100	-	PF
Output Capacitance	C _{oss}			-	483	-	PF
Reverse Transfer Capacitance	C _{rss}			-	28	-	PF
Switching Characteristics (Note 4)				•			
Turn-on Delay Time	t _{d(on)}			-	13.5	-	nS
Turn-on Rise Time	t _r	V_{DD} =40V, I_{D} =45A V_{GS} =10V, R_{G} =1.6 Ω		-	11	-	nS
Turn-Off Delay Time	t _{d(off)}			-	32	-	nS
Turn-Off Fall Time	t _f			-	11	-	nS
Total Gate Charge	Q_g	V _{DS} =40V,I _D =45A, V _{GS} =10V		-	51	-	nC
Gate-Source Charge	Q _{gs}			-	17.7		nC
Gate-Drain Charge	Q_{gd}			-	13.3		nC
Drain-Source Diode Characteristics							
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =	45A	-		1.2	V
Diode Forward Current (Note 2)	Is			-	-	90	Α
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F = 45A		-	60	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$		-	135	-	nC

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, $t \le 10$ sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25 $^{\circ}$ C,V_{DD}=40V,V_G=10V,L=0.5mH,Rg=25 Ω



Typical Electrical and Thermal Characteristics

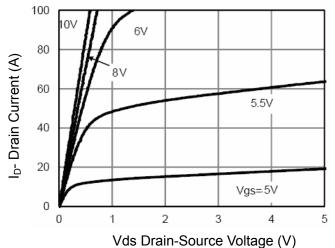


Figure 1 Output Characteristics

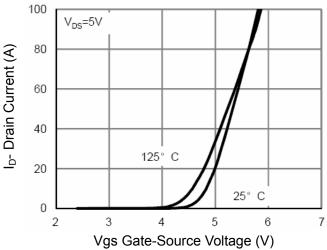


Figure 2 Transfer Characteristics

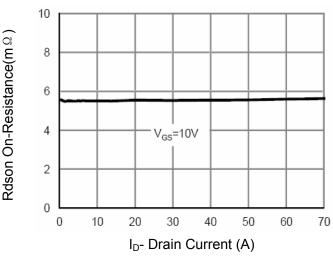


Figure 3 Rdson- Drain Current

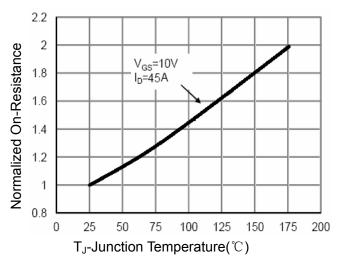


Figure 4 Rdson-Junction Temperature

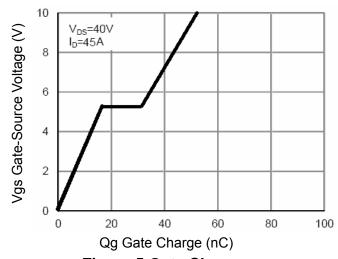


Figure 5 Gate Charge

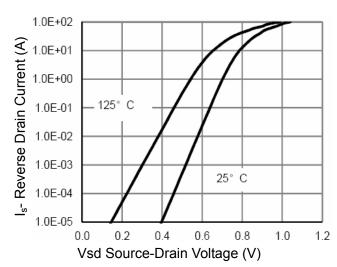


Figure 6 Source- Drain Diode Forward



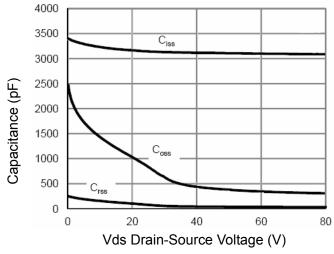


Figure 7 Capacitance vs Vds

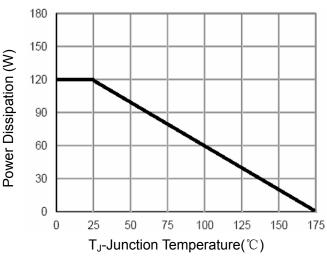


Figure 9 Power De-rating

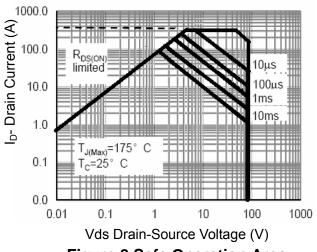


Figure 8 Safe Operation Area

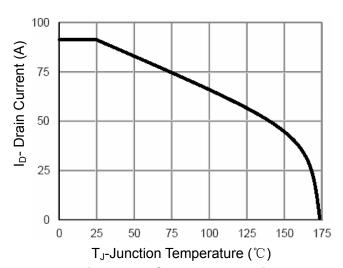


Figure 10 Current De-rating

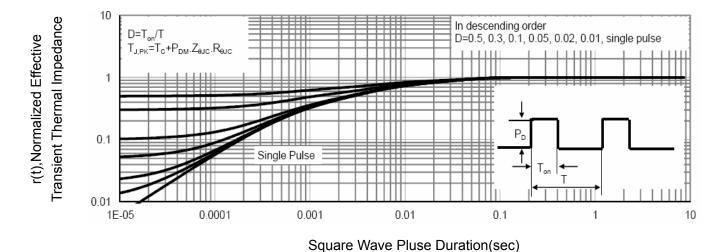
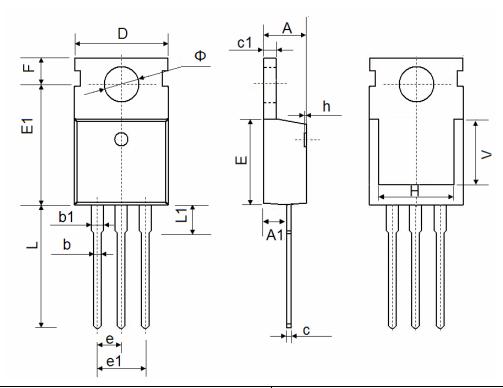


Figure 11 Normalized Maximum Transient Thermal Impedance



TO-220-3L Package Information



Cumbal	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
Е	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.540	TYP.	0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	6.900 REF.		0.276 REF.		
Ф	3.400	3.800	0.134	0.150	



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